TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCX32FT, TC74VCX32FK

Low-Voltage Quad 2-Input OR Gate with 3.6-V Tolerant Inputs and Outputs

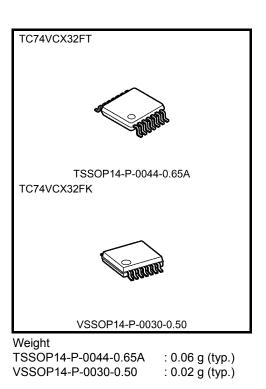
The TC74VCX32FT/FK is a high-performance CMOS 2-input OR gate which is guaranteed to operate from 1.2-V to 3.6-V. Designed for use in 1.5V, 1.8V, 2.5V or 3.3V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to 3.6 V.

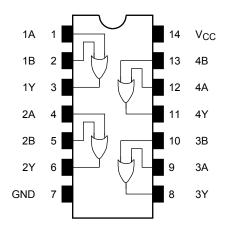
All inputs are equipped with protection circuits against static discharge.

Features

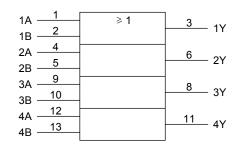
- Low-voltage operation: V_{CC} = 1.2 to 3.6 V
- High-speed operation: $t_{pd} = 2.8 \text{ ns} (max) (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
 - $t_{pd} = 3.7 \text{ ns} (\text{max}) (\text{V}_{CC} = 2.3 \text{ to } 2.7 \text{ V})$
 - $t_{pd} = 7.4 \text{ ns} (\text{max}) (\text{V}_{\text{CC}} = 1.65 \text{ to} 1.95 \text{ V})$
 - $t_{pd} = 14.8 \text{ ns (max)} (V_{CC} = 1.4 \text{ to } 1.6 \text{ V})$
 - $t_{pd} = 37.0 \text{ ns} (\text{max}) (\text{V}_{CC} = 1.2 \text{ V})$
- Output current: $I_{OH}/I_{OL} = \pm 24 \text{ mA} \text{ (min)} (V_{CC} = 3.0 \text{ V})$
 - $: I_{OH}/I_{OL} = \pm 18 \text{ mA} (min) (V_{CC} = 2.3 \text{ V})$
 - $: I_{OH}/I_{OL} = \pm 6 \text{ mA (min)} (V_{CC} = 1.65 \text{ V})$ $: I_{OH}/I_{OL} = \pm 2 \text{ mA (min)} (V_{CC} = 1.4 \text{ V})$
- Latch-up performance: -300 mA
- ESD performance: Machine model $\geq \pm 200 \text{ V}$
 - Human body model $\geq \pm 2000 \text{ V}$
- Package: TSSOP and VSSOP (US)
- 3.6-V tolerant function and power-down protection provided on all inputs and outputs



Pin Assignment (top view)



IEC Logic Level



Truth Table

Inp	uts	Outputs
А	В	Y
L	L	L
L	Н	н
Н	L	н
Н	Н	Н

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	-0.5 to 4.6	V
DC input voltage	V _{IN}	-0.5 to 4.6	V
		-0.5 to 4.6 (Note 2)	
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5 (Note 3)	V
Input diode current	I _{IK}	-50	mA
Output diode current	IOK	±50 (Note 4)	mA
DC output current	IOUT	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: $V_{CC} = 0 V$

Note 3: High or low state. $I_{\mbox{OUT}}$ absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	1.2 to 3.6	V	
Input voltage	V _{IN}	-0.3 to 3.6	V	
Output voltage	Vout	0 to 3.6 (Note 2)	V	
Output voltage	V001	0 to V _{CC} (Note 3)		
		±24 (Note 4)		
Output current		±18 (Note 5)		
Output current	IOH/IOL	±6 (Note 6)	mA	
		±6 (Note 7)		
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 8)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 2: $V_{CC} = 0 V$

Note 3: High or low state

Note 4: $V_{CC} = 3.0$ to 3.6 V

Note 5: $V_{CC} = 2.3$ to 2.7 V

Note 6: $V_{CC} = 1.65$ to 1.95 V

Note 7: $V_{CC} = 1.4$ to 1.6 V

Note 8: $V_{IN}=0.8$ to 2.0 V, $V_{CC}=3.0$ V

Electrical Characteristics

DC Characteristics (Ta = –40 to 85°C, 2.7 V < V_{CC} \leq 3.6 V)

Characteristi	<u></u>	Symbol	Test Co	Test Condition		Min	Мах	Unit
Characteriotico		Symbol	Test Oc	Test Condition		IVIIII	Max	Office
Input voltage	H-level	VIH	-	_	2.7 to 3.6	2.0		v
	L-level	VIL	_	_	2.7 to 3.6	_	0.8	v
Output voltage				I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2	_	
	H-level	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_	
				$I_{OH} = -18 \text{ mA}$	3.0	2.4	_	v
				I _{OH} = -24 mA	3.0	2.2		
	L-level Voi		$I_{OL} = 100 \ \mu A$	2.7 to 3.6	_	0.2		
			$I_{OL} = 12 \text{ mA}$	2.7	_	0.4		
	L-level	V _{OL}	$V_{IN} = V_{IL}$	$I_{OL} = 18 \text{ mA}$	3.0	_	0.4	
				$I_{OL} = 24 \text{ mA}$	3.0	_	0.55	
Input leakage current		I _{IN}	$V_{IN} = 0$ to 3.6 V		2.7 to 3.6	_	±5.0	μA
Power-off leakage curr	ent	I _{OFF}	V_{IN} , $V_{OUT} = 0$ to 3.6 \	/	0	_	10.0	μA
		Icc	$V_{IN} = V_{CC}$ or GND		2.7 to 3.6		20.0	
Quiescent supply curre	Quiescent supply current		$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		2.7 to 3.6	_	±20.0	μA
Increase in I _{CC} per inp	ut	Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6		750	

DC Characteristics (Ta = -40 to 85°C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characterist	ice	Symbol	Test	Condition	-	Min	Max	Unit
		Cymbol	1030			IVIIII	Max	Offic
Input voltage	H-level	VIH		—	2.3 to 2.7	1.6	_	V
input voltage	L-level	VIL		_	2.3 to 2.7	_	0.7	v
ŀ				I _{OH} = −100 μA	2.3 to 2.7	V _{CC} - 0.2	_	
	H-level Vo	Voh	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -6 mA	2.3	2.0		· ·
				I _{OH} = -12 mA	2.3	1.8	_	
Output voltage				I _{OH} = -18 mA	2.3	1.7		
			$V_{IN} = V_{IL}$	$I_{OL} = 100 \ \mu A$	2.3 to 2.7	_	0.2	
	L-level	V _{OL}		$I_{OL} = 12 \text{ mA}$	2.3	_	0.4	
				I _{OL} = 18 mA	2.3	_	0.6	
Input leakage current		I _{IN}	$V_{IN} = 0$ to 3.6 V		2.3 to 2.7	_	±5.0	μA
Power-off leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	_	10.0	μA
			V _{IN} = V _{CC} or GND		2.3 to 2.7	_	20.0	
Quiescent supply curre	5111	Icc	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		2.3 to 2.7		±20.0	μA

DC Characteristics (Ta = -40 to 85°C, 1.65 V \leq V_{CC} < 2.3 V)

Characteristics		Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Inputivoltago	H-level	VIH	н —		1.65 to 2.3	$0.65 \times V_{CC}$	_	V
Input voltage		V _{IL}	_		1.65 to 2.3		$0.2 \times V_{CC}$	v
	H-level V _{OH}	VoH	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -100 μA	1.65 to 2.3	V _{CC} - 0.2		v
Output voltage				I _{OH} = -6 mA	1.65	1.25	_	
	L-level	Mai	$V_{IN} = V_{IL}$	I _{OL} = 100 μA	1.65 to 2.3	_	0.2	
	L-IEVEI	V _{OL}		I _{OL} = 6 mA	1.65	_	0.3	
Input leakage current		I _{IN}	$V_{IN} = 0$ to 3.6 V		1.65 to 2.3	_	±5.0	μA
Power-off leakage current		I _{OFF}	V_{IN} , $V_{OUT} = 0$ to 3.6 V	,	0	_	10.0	μA
Quiessant supply surrent			$V_{IN} = V_{CC} \text{ or } GND$		1.65 to 2.3	_	20.0	μA
Quiescent supply curre	111	Icc	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		1.65 to 2.3	_	±20.0	μA

DC Characteristics (Ta = -40 to 85°C, 1.4 V \leq V_{CC} < 1.65 V)

Characteristics		Symbol	Test Co	andition		Min	Max	Unit
		Cymbol	100100			IVIIII	max	
Input voltage	H-level		_	_		$0.65 \times V_{CC}$	_	V
input voltage	L-level	VIL	_		1.4 to 1.65		$\begin{array}{c} 0.05 \times \\ V_{CC} \end{array}$	v
	H-level V _{OH}	VIN = VIH or VII	I _{OH} = -100 μA	1.4 to 1.65	V _{CC} - 0.2	_		
Output voltage		_		$I_{OH} = -2 \text{ mA}$	1.4	1.05	_	V
·		Mai	$V_{IN} = V_{IL}$	I _{OL} = 100 μA	1.4 to 1.65	_	0.05	
	L-level	V _{OL}		$I_{OL} = 2 \text{ mA}$	1.4	_	0.35	
Input leakage current		I _{IN}	$V_{IN} = 0$ to 3.6 V		1.4 to 1.65	_	±5.0	μA
Power-off leakage current		I _{OFF}	V_{IN} , $V_{OUT} = 0$ to 3.6 V	1	0	_	10.0	μA
			$V_{IN} = V_{CC}$ or GND		1.4 to 1.65	_	20.0	
Quiescent supply curre	111	Icc	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		1.4 to 1.65	_	±20.0	μA

DC Characteristics (Ta = -40 to 85°C, 1.2 V \leq V_{CC} < 1.4 V)

Characteristics		Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	VIH	_	-	1.2 to 1.4	0.8× V _{CC}	_	V
input voltage	L-level	VIL	_	_			$\begin{array}{c} 0.05 \times \\ V_{CC} \end{array}$	v
Output voltage	H-level	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -100 \ \mu A$		1.2	V _{CC} - 0.1	_	V
	L-level	V _{OL}	$V_{IN} = V_{IL}$	I _{OL} = 100 μA	1.2	_	0.05	
Input leakage current		I _{IN}	$V_{IN} = 0$ to 3.6 V		1.2		±5.0	μA
Power-off leakage curr	ent	IOFF	V_{IN} , $V_{OUT} = 0$ to 3.6 V		0		10.0	μA
Quiescent supply current		laa	$V_{IN} = V_{CC} \text{ or } GND$		1.2		20.0	μA
Quiescent supply curre	111	ICC	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		1.2	_	±20.0	μΑ

AC Characteristics (Ta = -40 to 85°C, input: $t_r = t_f = 2.0$ ns) (Note 1)

Characteristics	Symbol	Tes	Test Condition			Max	Unit
				V _{CC} (V)			
Propagation delay time			$C_{I} = 15 pF, R_{I} = 2 k\Omega$	1.2	3.0	37.0	
	+		$O_{L} = 10 \text{pr}$, $N_{L} = 2 \text{Km}^2$	1.5 ± 0.1	2.0	14.8	
	t _{pLH} t _{pHL}	Figure 1, Figure 2		$\textbf{1.8} \pm \textbf{0.15}$	1.5	7.4	ns
	γρπε		$C_L = 30 \text{ pF}, \text{ R}_L = 500 \Omega$	2.5 ± 0.2	0.8	3.7	
				$\textbf{3.3}\pm\textbf{0.3}$	0.6	2.8	
			$C_L = 15 \text{ pF}, \text{ R}_L = 2 \text{ k}\Omega$	1.2		1.5	
	+			1.5 ± 0.1		1.5	
Output to output skew	t _{osLH}	(Note 2)		1.8 ± 0.15		0.5	ns
	t _{osHL}		$C_L = 30 \text{ pF}, \text{ R}_L = 500 \Omega$	2.5 ± 0.2		0.5	
				$\textbf{3.3}\pm\textbf{0.3}$		0.5	

Note 1: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design. $(t_{osLH} = |t_{pLHm} - t_{pLHn}|, \ t_{osHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.0 \text{ ns}$, $C_L = 30 \text{ pF}$)

Characteristics	Symbol	Test Condition			Тур.	Unit
Characteristics	Cymbol			$V_{CC}(V)$	Typ.	Offic
		$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note)	1.8	0.25	
Quiet output maximum dynamic V _{OL}	V _{OLP}	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	2.5	0.6	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	3.3	0.8	
	V _{OLV}	$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	1.8	-0.25	
Quiet output minimum dynamic V _{OL}		$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	2.5	-0.6	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	3.3	-0.8	
		V _{IH} = 1.8 V, V _{IL} = 0 V	(Note)	1.8	1.5	
Quiet output minimum dynamic V _{OH}	V _{OHV}	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	2.5	1.9	V
011		$V_{IH} = 3.3 V, V_{IL} = 0 V$	(Note)	3.3	2.2	

Note: Parameter guaranteed by design.

Capacitive Characteristics ($Ta = 25^{\circ}C$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	—	1.8, 2.5, 3.3	6	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (Not	e) 1.8, 2.5, 3.3	20	pF

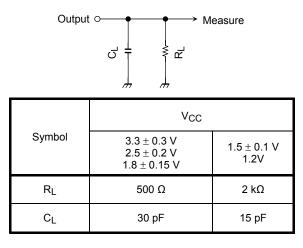
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4$ (per gate)

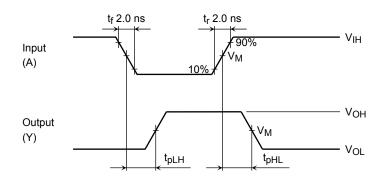
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AC Test Circuit





AC Waveform



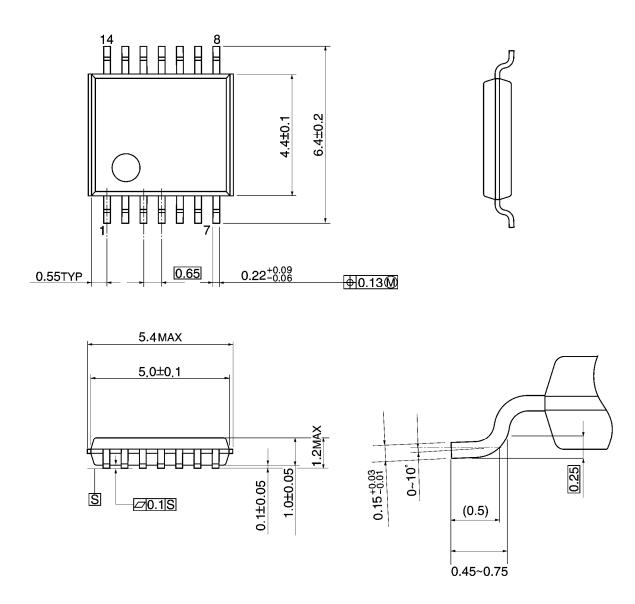
Symbol			V _{CC}		
Symbol	$3.3\pm0.3\;V$	$2.5\pm0.2\;V$	$1.8\pm0.15\;V$	$1.5\pm0.1~\text{V}$	1.2 V
VIH	2.7 V	V _{CC}	V _{CC}	V _{CC}	V _{CC}
VM	1.5 V	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2

Figure 2 t_{pLH}, t_{pHL}

Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm



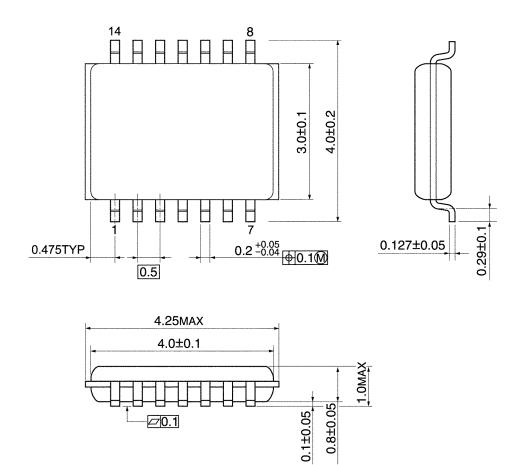
Weight: 0.06 g (typ.)

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Package Dimensions

VSSOP14-P-0030-0.50

Unit: mm



Weight: 0.02 g (typ.)

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